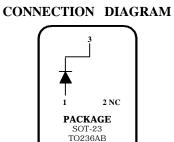


SEMICONDUCTOR TM

# 3 5HF

1

2



## Schottky Barrier Diode

PACKAGE

SOT-23 TO-236AB (Low)

Sourced from Process GE

## Absolute Maximum Ratings\* TA = 25°C unless otherwise noted

Sym	Parameter	Value	Units
T <sub>sta</sub>	Storage Temperature	-55 to +150	oC
TJ	Operating Junction Temperature	-55 to +125	Oo
W <sub>iv</sub>	Working Inverse Voltage	35	V
P <sub>F</sub>	Forward Power Dissipation @ $T_A = 25^{\circ}C$	200	mW
	Derate above 25°C	2.0	Mw/ <sup>o</sup> C

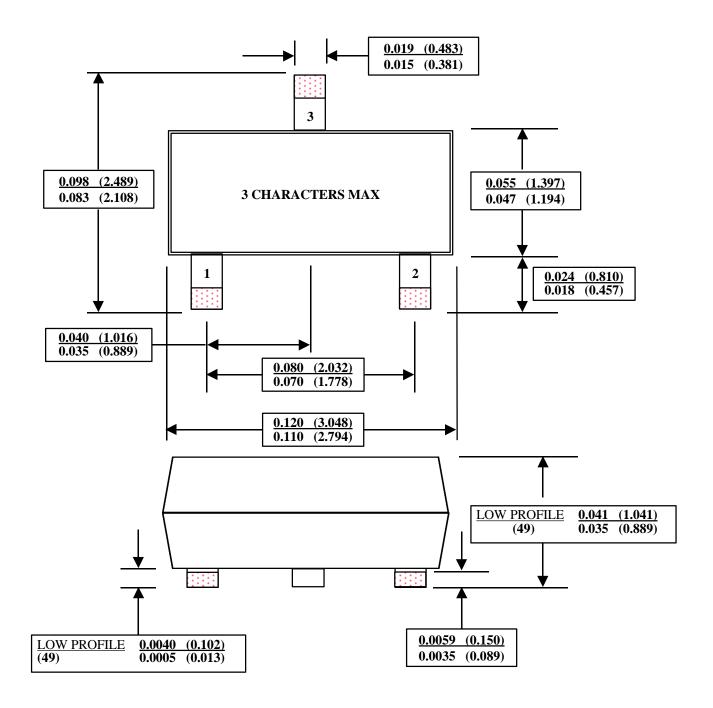
\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired

## ADVANCED INFORMATION ONLY NOT IN PRODUCTION

**Electrical Characteristics** TA = 25<sup>o</sup>C unless otherwise noted

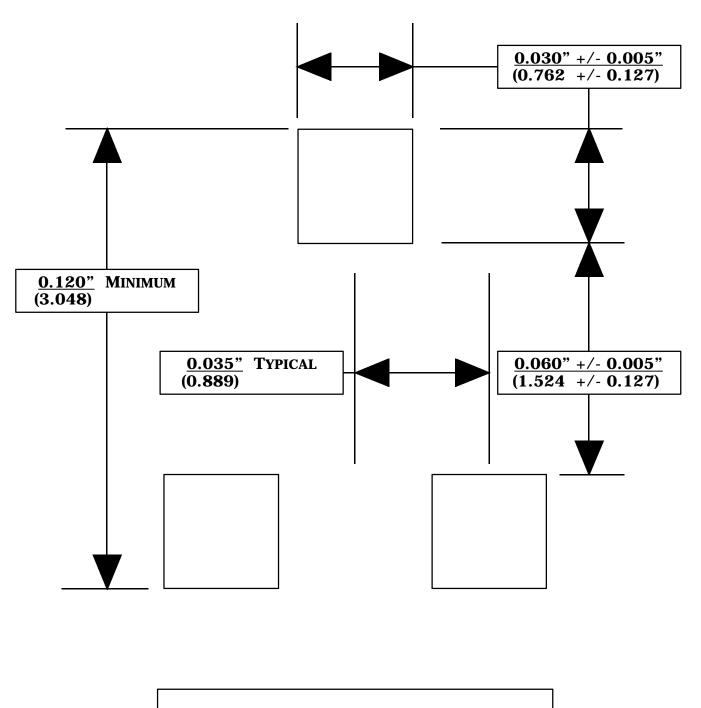
SYM	CHARACTERISTICS	ΜΙΝ	MAX	UNITS	TEST CONDITIONS
B <sub>v</sub> Breakdown Voltage		70		V	$I_R = 10 \text{ uA}$
I <sub>R</sub> Rev	I <sub>R</sub> Reverse Leakage		200	nA	V <sub>R</sub> = 35 V
V <sub>F</sub> Forward Voltage			500 1.0	mV V	I <sub>F</sub> = 1.0 mA I <sub>F</sub> = 10 mA
С <sub>т</sub> Сар	C <sub>T</sub> Capacitance		1.0	pF	$V_{R} = 20 V$ f = 1.0 MHz
© 1997 Fairchild Semicondu	actor Corporation				





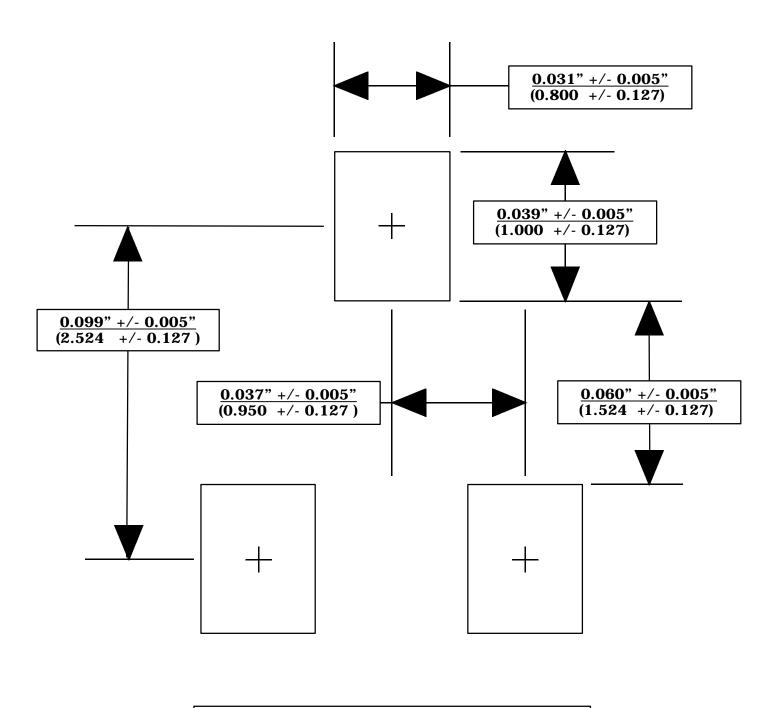






## RECOMMENDED SOLDER PADS FOR SOT-23







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